



IEA Technology Collaboration Programme
on Energy Efficient End-Use Equipment



Power Electronic Conversion
Technology Annex PECTA

The background is a composite image. The left side shows server racks with numerous cables plugged into ports, overlaid with a semi-transparent blue-green filter. The right side shows a white front-loading washing machine, overlaid with a semi-transparent green filter. A diagonal hatched pattern separates the two images at the top.

Wide Band Gap Semiconductors – the future of power electronics

(based on PECTA –
the Power Electronic Conversion Annex of the IEA TCP 4E)

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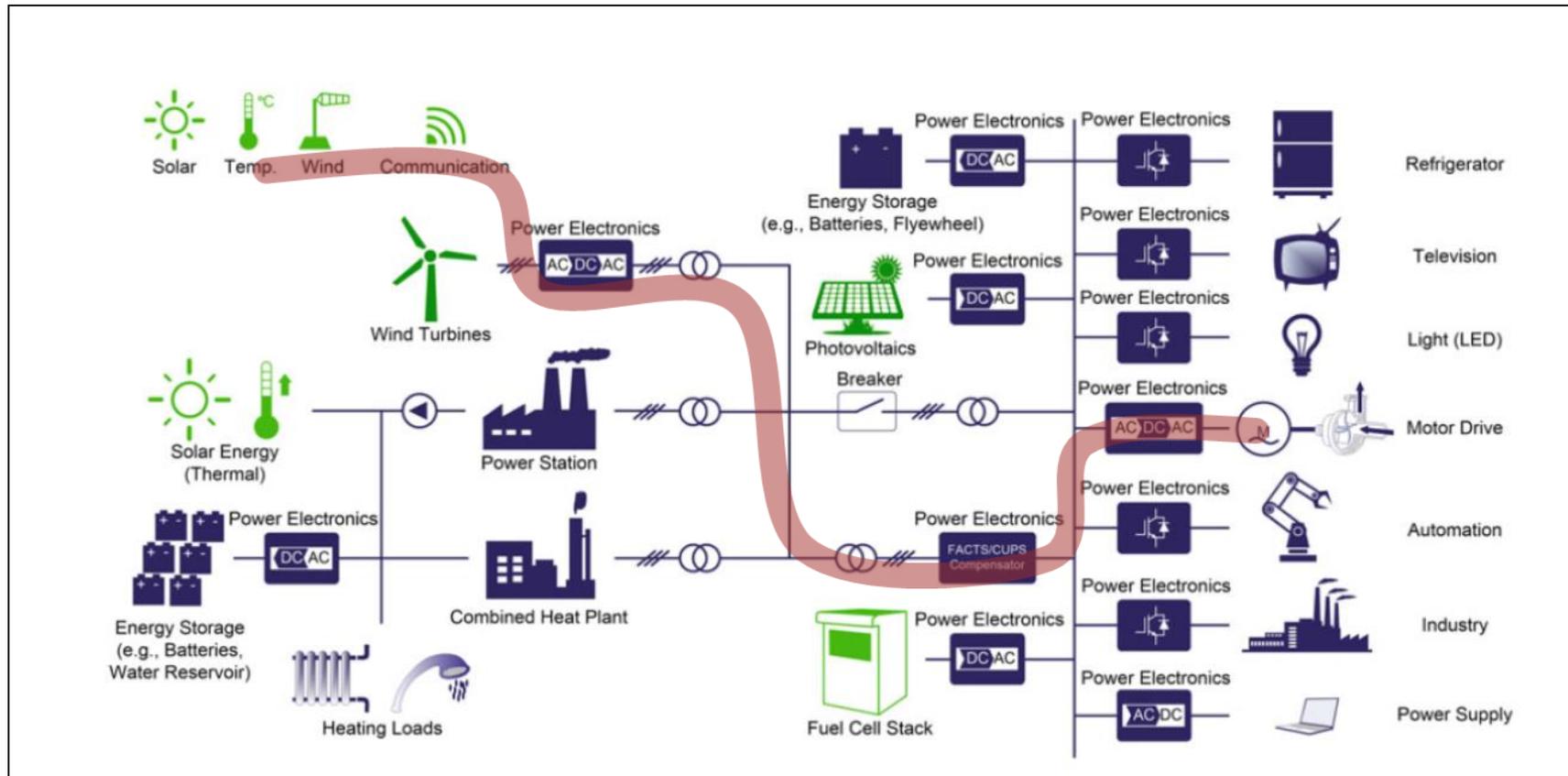
iea-4e.org

International Context (IEA-TCP)

- **4E: Energy Efficient End-Use Equipment**
- **14 Countries and the EU-Commission** are currently member of the 4E TCP (Countries: AU, AT, CA, CN, DK, FR, JP, KR, NL, NZ, CH, SE, UK, US)
- 4 ongoing Annexes:
 - EMSA: Electric Motor Systems Annex
 - EDNA: Electronic Devices and Networks Annex
 - SSL: Solid State Lighting Annex
 - PECTA: Power Electronic Conversion Technology Annex
- 2 major initiatives:
 - PEET: Product Energy Efficiency Trends
 - cda: Connected Device Alliance
- **Link:** <https://www.iea-4e.org/>



Technical context: Power Electronic is everywhere and efficiency is most relevant



PECTA – available results

- **Publication**

Wide Band Gap Technology:
Efficiency Potential and Application Readiness Map

Officially released: May 2020, 100 pages

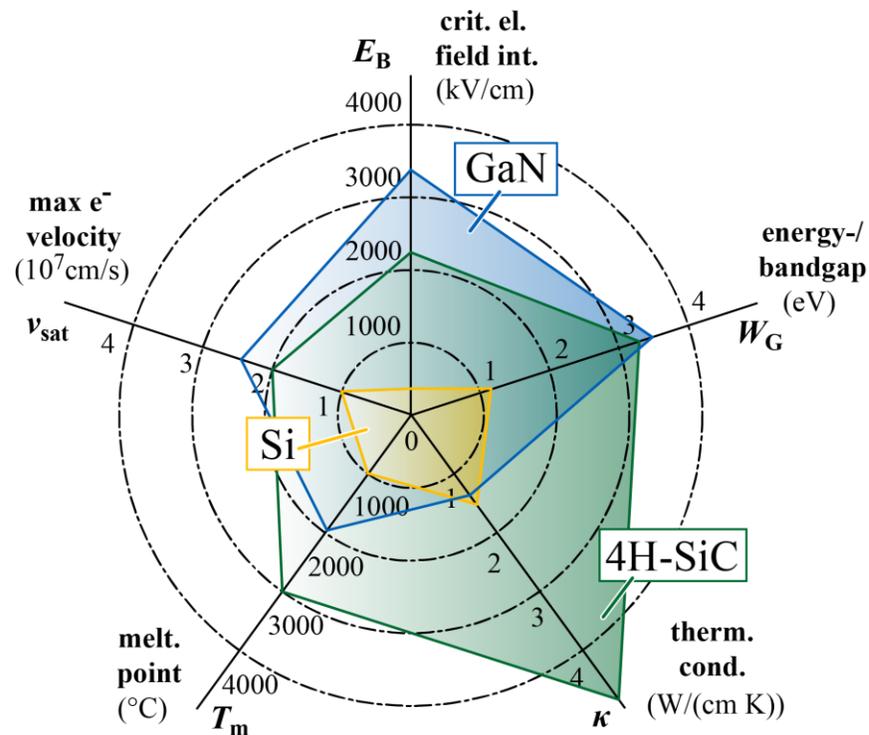
- **Outline**

- Introduction
- Applications in Focus
- Advantages of WBG in the Applications
- Existing Roadmaps
- Application Readiness Map
- WBG-Technology Challenges
- Potential Energy Savings for Selected Applications
- Exploring Policies for WBG Technology
- Key Findings and Outlook



PECTA – available results

- **Wide Bandgap – An Overview (SiC- and GaN-based semiconductors)**



Higher system efficiency

Improved power density

Faster system response

Increased blocking voltage capability

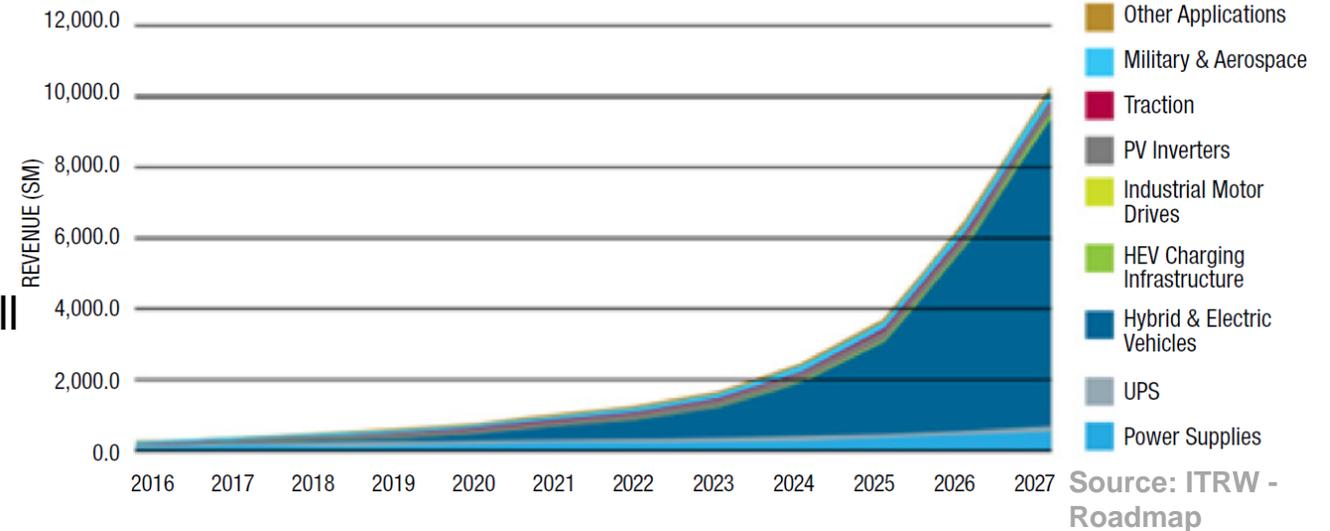
Suitable for low-, medium- and high-power systems

CO₂ reduction

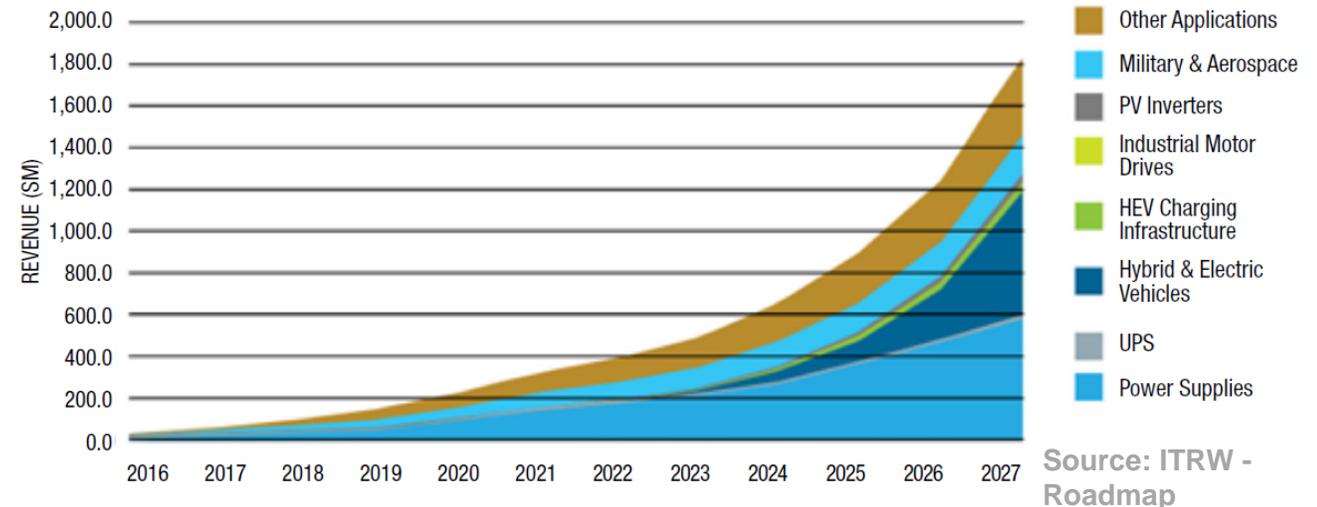
PECTA – available results

- **Market prediction – SiC:**
 - Compound annual growth rate (CAGR) 31% - (2018-2023)
 - According to Yole: Transistors will be key drivers
 - Automotive main driver for SiC Market (traction inverters, on-board chargers, charging infrastructure,...)
- **Market prediction – GaN:**
 - CAGR 55% - (2018-2023)
 - Power supplies are short-term drivers
 - Long-term: EVs, motor drives, wireless charging,...

THE SiC POWER CONDUCTOR MARKET

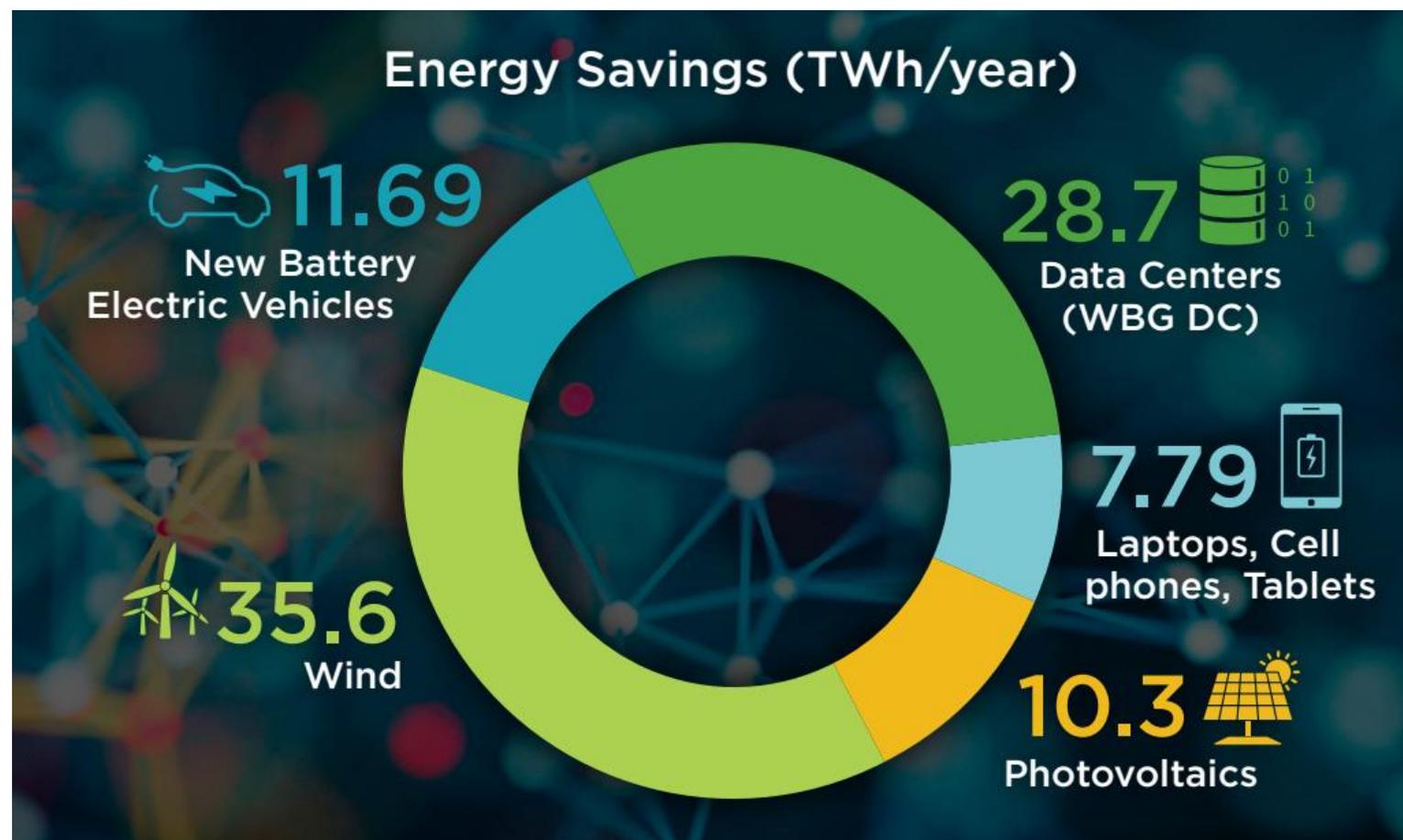


THE GaN SEMICONDUCTOR MARKET



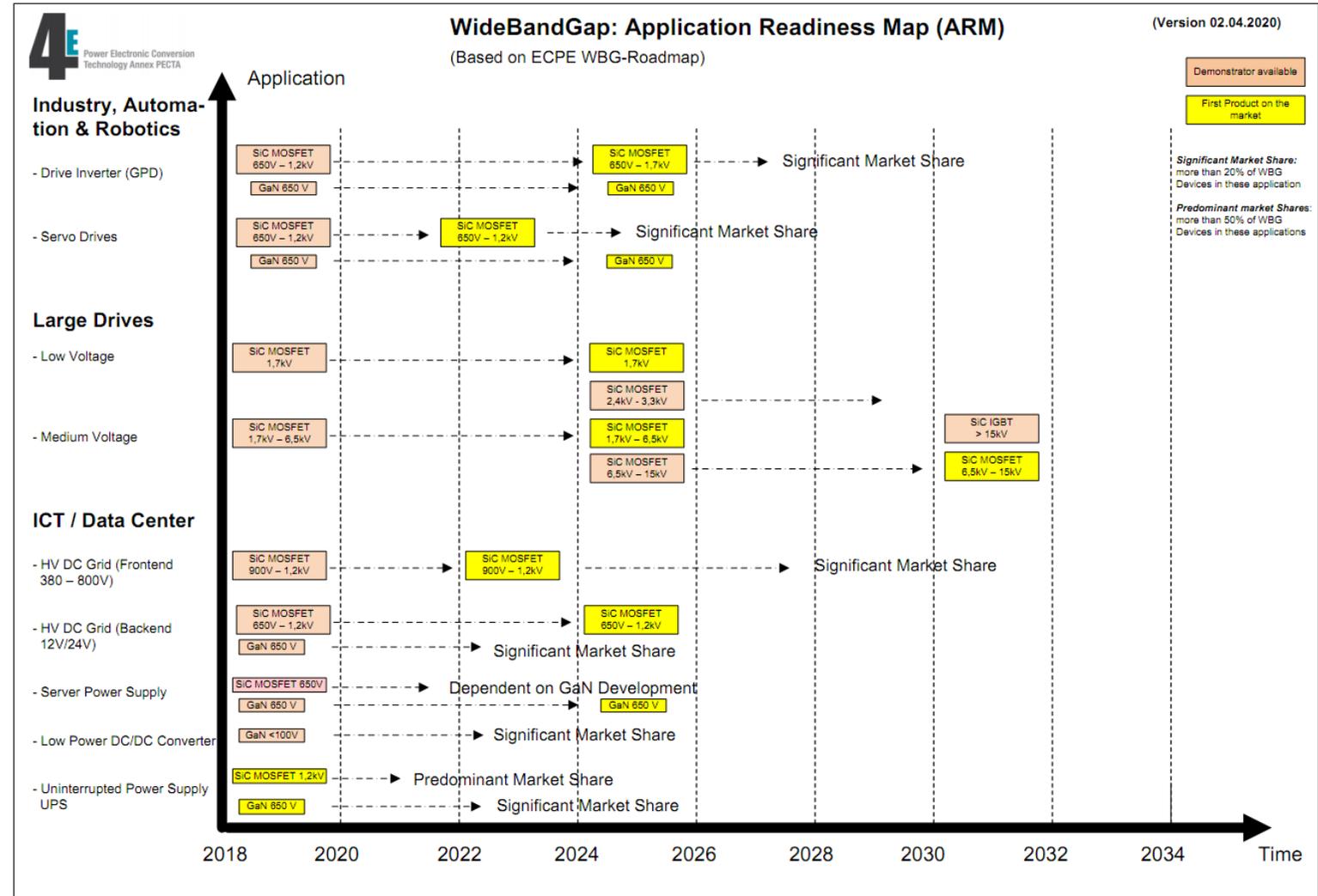
PECTA – available results

- Energy Savings of selected applications



PECTA – available results

- **Application Readiness Map (ARM)**
- This ARM was as well the basis for an ARM in the HST-TCP
- *Indirect interaction between TCPS via CH-Representative*



PECTA – available results

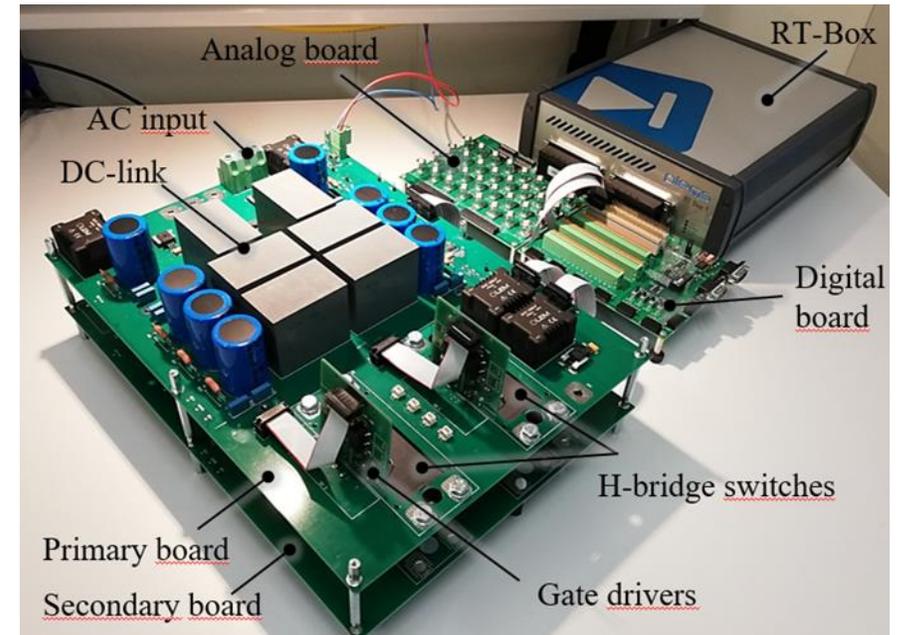
- **Policy**
 - Listing of different types and sub-types of instruments
 - WBG still at a very early stage for many applications (currently RD&D)

Main Type		Sub Type 1		Sub type 2		Main Type		Sub Type 1		Sub type 2							
Economic Instrument	E	Direct investment	D	Funds to sub-national governments	F	Policy support	P	Institution creation	I	Codes & standards	C	Building codes & standards	B				
				Infrastructure investments	I			Strategic planning	S					Product standards	P		
				Procurement rules	P			Auditing	A							Sectoral standards	S
				RD&D Funding	R											Vehicle fuel economy & emissions standards	V
		Fiscal/Financial incentives	F	Feed-in tariffs/premiums	F	Regulatory instruments	R	Monitoring	M								
				Grants and subsidies	G			Obligation schemes	Ob								
				Loans	L			Other mandatory requirements	O								
				Tax relief	Tr			Demonstration project	D								
				Taxes	T							Technology deployment and diffusion	Dp				
				User charges	C							Technology development	Dv				
		Market-based instruments	M	GHG emissions allowances	A	Research, development & deployment (RD&D)	RD										
				Green certificates	G												
White certificates	W																
Information & education	I	Implementation advice/Aid	A	Voluntary approaches	V	Negotiated agreements (Public-private sector)	N										
		Information provision	I			Public voluntary schemes	V										
		Performance label	L			Comparison label	C	Unilateral commitments (Private sector)	C								
						Endorsement label	E										
		Professional training & qualification	T														

IEA 4E EDNA Annex: “Encouraging Intelligent Efficiency - Study of policy opportunities”, 2017

PECTA – available results

- **WBG-technology challenges (= hurdles)**
 - Temperature increase
 - Gate voltage limits (particular GaN)
 - *Reliability*
 - High switching frequency
 - New packages and topology solutions
 - *Cost*
 - Shortage of materials (particular SiC)
 - Wafer diameter
 - Standardization (Comparability)



PECTAs' goal and ongoing activities (2020 – 2024)

PECTA goals: Collecting and analyzing information about new wide band gap (WBG) based power electronic devices;
Coordinating of international approaches that promote WBG-based power electronics
Developing greater understanding and action amongst governments and policy makers.

Tasks:

- Task A:* Completing and updating available efficiency figures
- Task B:* Energy and environmental related life cycle assessment (LCA)
- Task C:* Revision of elaborated application readiness maps (ARMs)
- Task D:* Policy measures and mapping with applications on a timeline
- Task E:* Standards to support the WBG-market entrance
- Task F:* Measurement of power supply efficiency

GaN-based Power Electronics for Energy Efficiency Applications

EPFL, Completion Q1 2019 (<https://www.aramis.admin.ch/Texte/?ProjectID=36837>)

Investigating the increase of system efficiency in power conversion by using GaN semiconductor technology

High-efficiency power converters for potentially-large energy-savings applications

EPFL, Completion Q2 2020 (<https://www.aramis.admin.ch/Texte/?ProjectID=40293>)

Design and demonstration of power converter circuits with large energy saving potential for demanding applications such as PV microinverters and LED-based street lighting

Advanced SiC Material for Power Electronic Devices (Ampere)

FHNW / HITACHI-ENERGY, Completion Q3 2021 (<https://www.aramis.admin.ch/Texte/?ProjectID=40193>)

Development of advanced high voltage SiC device technologies that go beyond the state of the art. The focus was on 6.5 and 10 kV SiC switches and diodes.

Roadrunner Commercial Vehicle Inverter and Testing on eBus Line

ABB / RVBW / FHNW, Completion 2022 / 2023 (extension)

As part of the P+D project "Roadrunner", a fleet of eBuses was to be equipped with a new power converter based on Silicon Carbide (SiC) semiconductors;

Swiss Hybrid Inverter

FHNW, Completion Q3 2022

Simulation, construction and measurement of a prototype Si IGBT/SiC MOSFET cross-hybrid-switch with 1,2 kV and 100 kW

IEA PECEA: Analysis and Loss Measurements of WBG-based Devices

EPFL, Completion Q2 2024

Development of basics for WBG devices as a basis for future reproducible measurements (prerequisite for standardization)

Optimized SiC PV-Converter

ZHAW / AIT, Completion Q4 2023 / Q1 2024

Construction of a PV inverter in the power range of 5-10kW based on a SiC MOSFET bridge from Infineon and comparison with a commercial Si-based PV inverter

Optimal, application-relevant and system efficiency of SiC-pump-drive

FHNW, Grundfos Pumpen AG, Completion Q 2025

Development of efficient SiC converter in the range of several kW for water pumps (or water circulated pump)

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